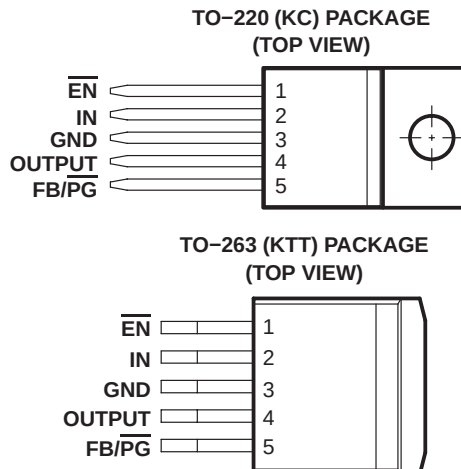


TPS75715, TPS75718, TPS75725, TPS75733 WITH POWER GOOD AND TPS75701 FAST-TRANSIENT RESPONSE 3-A LOW-DROPOUT VOLTAGE REGULATORS

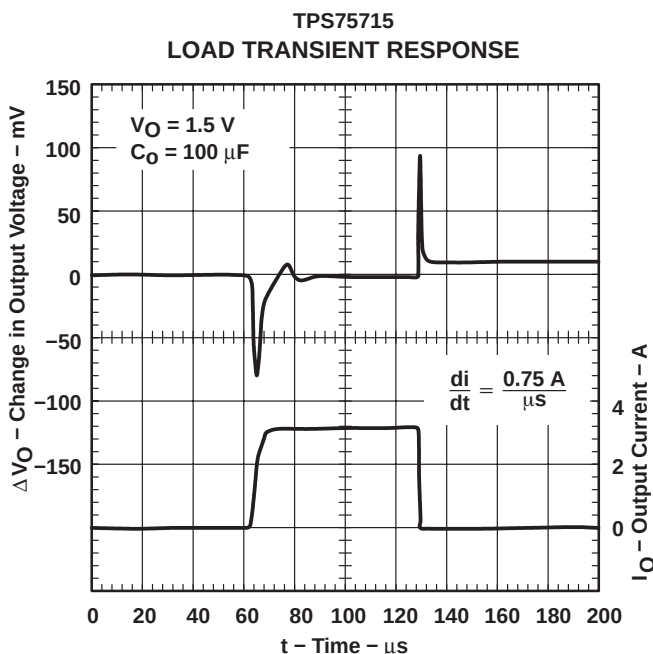
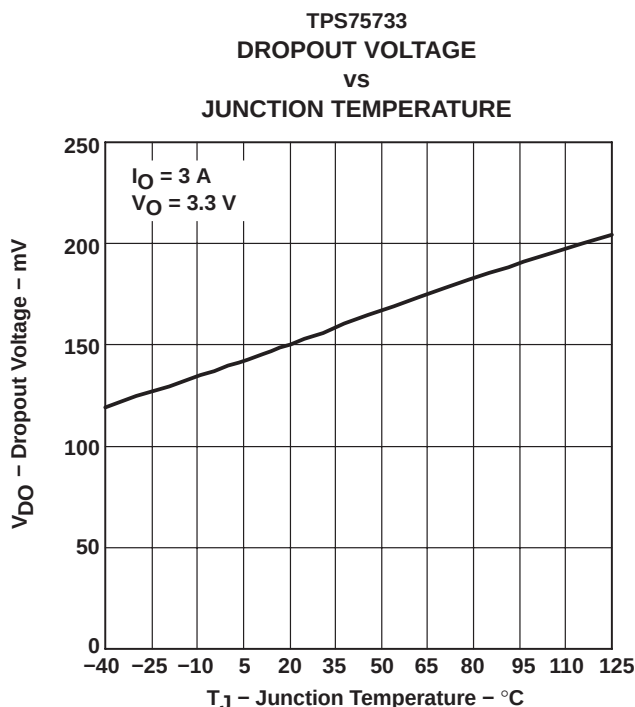
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- 3-A Low-Dropout Voltage Regulator
- Available in 1.5-V, 1.8-V, 2.5-V, and 3.3-V Fixed-Output and Adjustable Versions
- Open Drain Power-Good ($\overline{\text{PG}}$) Status Output (Fixed Options Only)
- Dropout Voltage Typically 150 mV at 3 A (TPS75733)
- Low 125 μA Typical Quiescent Current
- Fast Transient Response
- 3% Tolerance Over Specified Conditions for Fixed-Output Versions
- Available in 5-Pin TO-220 and TO-263 Surface-Mount Packages
- Thermal Shutdown Protection



description

The TPS757xx family of 3-A low dropout (LDO) regulators contains four fixed voltage option regulators with integrated power-good ($\overline{\text{PG}}$) and an adjustable voltage option regulator. These devices are capable of supplying 3 A of output current with a dropout of 150 mV (TPS75733). Therefore, the device is capable of performing a 3.3-V to 2.5-V conversion. Quiescent current is 125 μA at full load and drops down to less than 1 μA when the device is disabled. The TPS757xx is designed to have fast transient response for large load current changes.



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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TPS75715, TPS75718, TPS75725, TPS75733 WITH POWER GOOD AND TPS75701 FAST-TRANSIENT RESPONSE 3-A LOW-DROPOUT VOLTAGE REGULATORS

SLVS306E – NOVEMBER 2000 – REVISED FEBRUARY 2009

description (continued)

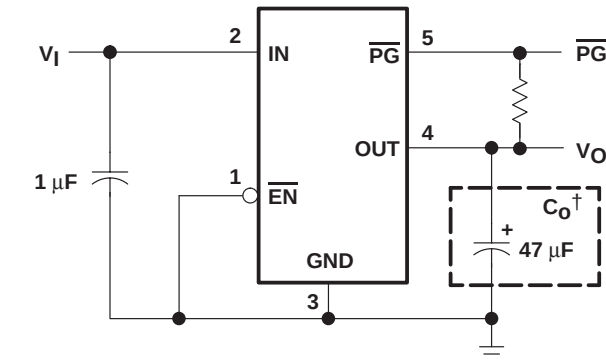
Because the PMOS device behaves as a low-value resistor, the dropout voltage is low (typically 150 mV at an output current of 3 A for the TPS75733) and is directly proportional to the output current. Additionally, since the PMOS pass element is a voltage-driven device, the quiescent current is low and independent of output loading (typically 125 μ A over the full range of output current). These two key specifications yield a significant improvement in operating life for battery-powered systems.

The device is enabled when $\overline{\text{EN}}$ is connected to a low-level voltage. This LDO family also features a sleep mode; applying a TTL high signal to $\overline{\text{EN}}$ (enable) shuts down the regulator, reducing the quiescent current to less than 1 μ A at $T_J = 25^\circ\text{C}$. The power-good terminal ($\overline{\text{PG}}$) is an active low, open drain output, which can be used to implement a power-on reset or a low-battery indicator.

The TPS757xx is offered in 1.5-V, 1.8-V, 2.5-V, and 3.3-V fixed-voltage versions and in an adjustable version (programmable over the range of 1.22 V to 5 V). Output voltage tolerance is specified as a maximum of 3% over line, load, and temperature ranges. The TPS757xx family is available in a 5-pin TO–220 (KC) and TO–263 (KTT) packages.

AVAILABLE OPTIONS			
T_J	OUTPUT VOLTAGE (TYP)	TO–220 (KC)	TO–263(KTT)
–40°C to 125°C	3.3 V	TPS75733KC	TPS75733KTT
	2.5 V	TPS75725KC	TPS75725KTT
	1.8 V	TPS75718KC	TPS75718KTT
	1.5 V	TPS75715KC	TPS75715KTT
	Adjustable 1.22 V to 5 V	TPS75701KC	TPS75701KTT

NOTE: The TPS75701 is programmable using an external resistor divider (see application information). The KTT package is available taped and reeled. Add an R suffix to the device type (e.g., TPS75701KTTR) to indicate tape and reel.



† See application information section for capacitor selection details.

Figure 1. Typical Application Configuration (For Fixed Output Options)

SLVS306E – NOVEMBER 2000 – REVISED FEBRUARY 2009

[illegible]

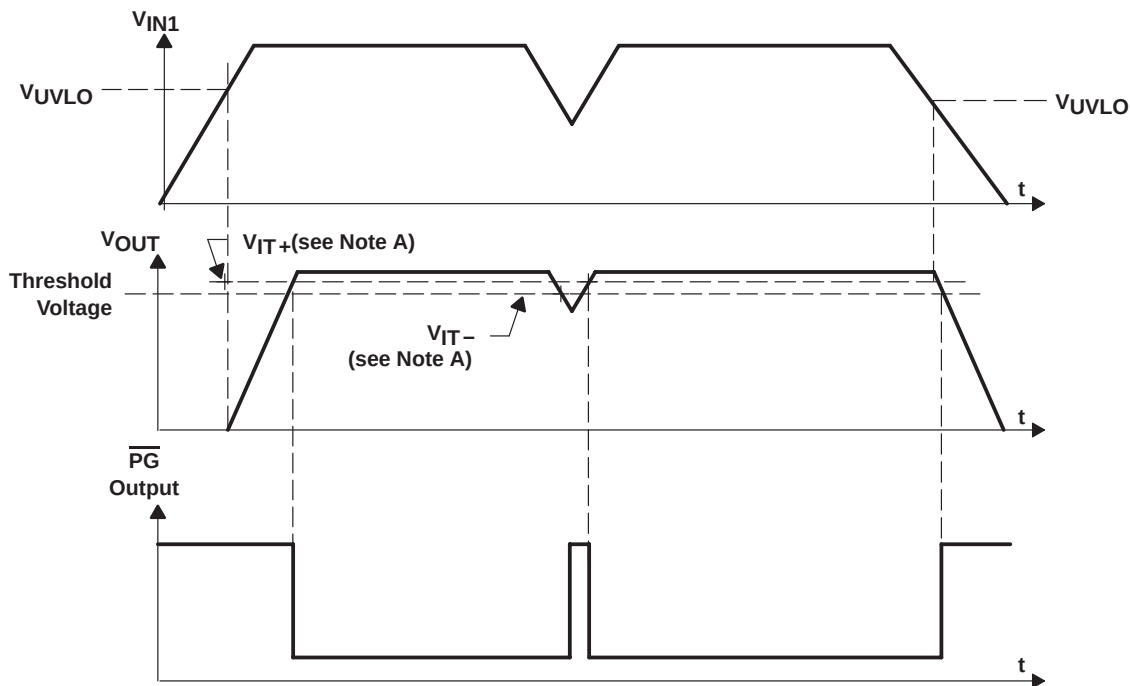
The schematic diagram illustrates a voltage regulator circuit with current limit and shutdown features. The input voltage V_{IN} is connected to the UVLO (Under-Voltage Lockout) block and the Bandgap Reference block. The $\overline{EN}$ (Enable) signal is inverted and connected to the UVLO block. The UVLO block outputs $\overline{UVLO}$ to an AND gate. The Bandgap Reference block provides a $V_{ref} = 1.22\text{ V}$ reference voltage to the inverting input of the error amplifier and to another AND gate. The Current Sense block monitors the output current and outputs $ILIM$ to the non-inverting input of the error amplifier. The error amplifier's output drives the base of the pass transistor. The output voltage V_{OUT} is taken from the load, which is connected to the emitter of the pass transistor. The output voltage is also divided by resistors $R1$ and $R2$ to provide feedback to the error amplifier. A thermal shutdown block is connected to the $\overline{UVLO}$ signal and the error amplifier. A falling edge delay block is connected to the $\overline{UVLO}$ signal and the error amplifier. The output of the falling edge delay block is connected to the base of the pass transistor and the $\overline{PG}$ (Programmable Gain) signal.

TERMINAL NAME	NO.	I/O	DESCRIPTION
EN	1	I	Enable input
FB/ $\overline{\text{PG}}$	5	I	Feedback input voltage for adjustable device/ $\overline{\text{PG}}$ output for fixed options
GND	3		Regulator ground
IN	2	I	Input voltage
OUTPUT	4	O	Regulated output voltage
Thermal Pad	–		Connect to GND or Float

TPS75715, TPS75718, TPS75725, TPS75733 WITH POWER GOOD AND TPS75701 FAST-TRANSIENT RESPONSE 3-A LOW-DROPOUT VOLTAGE REGULATORS

SLVS306E – NOVEMBER 2000 – REVISED FEBRUARY 2009

TPS757xx $\overline{\text{PG}}$ timing diagram



NOTE: V_{IT-} Trip voltage is typically 9% lower than the output voltage ($91\%V_O$). V_{IT-} to V_{IT+} is the hysteresis voltage.

detailed description

The TPS757xx family includes four fixed-output voltage regulators (1.5 V, 1.8 V, 2.5 V, and 3.3 V), and an adjustable regulator, the TPS75701 (adjustable from 1.22 V to 5 V). The bandgap voltage is typically 1.22 V.

pin functions

enable ($\overline{\text{EN}}$)

The $\overline{\text{EN}}$ terminal is an input which enables or shuts down the device. If $\overline{\text{EN}}$ is a logic high, the device will be in shutdown mode. When $\overline{\text{EN}}$ goes to logic low, the device will be enabled.

power-good ($\overline{\text{PG}}$)

The $\overline{\text{PG}}$ terminal for the fixed voltage option devices is an open drain, active low output that indicates the status of V_O (output of the LDO). When V_O reaches approximately 91% of the regulated voltage, $\overline{\text{PG}}$ will go to a low impedance state. It will go to a high-impedance state when V_O falls below approximately 89% (i.e. over load condition) of the regulated voltage. The open drain output of the $\overline{\text{PG}}$ terminal requires a pullup resistor.

feedback (FB)

FB is an input terminal used for the adjustable-output option and must be connected to the output terminal either directly, in order to generate the minimum output voltage of 1.22 V, or through an external feedback resistor divider for other output voltages. The FB connection should be as short as possible. It is essential to route it in such a way to minimize/avoid noise pickup. Adding RC networks between FB terminal and V_O to filter noise is not recommended because it may cause the regulator to oscillate.

TPS75715, TPS75718, TPS75725, TPS75733 WITH POWER GOOD AND TPS75701 FAST-TRANSIENT RESPONSE 3-A LOW-DROPOUT VOLTAGE REGULATORS

SLVS306E – NOVEMBER 2000 – REVISED FEBRUARY 2009

detailed description (continued)

input voltage (IN)

The V_{IN} terminal is an input to the regulator.

output voltage (OUTPUT)

The V_{OUTPUT} terminal is an output to the regulator.

absolute maximum ratings over operating junction temperature range (unless otherwise noted)[†]

Input voltage range [‡] , V_I	–0.3 V to 6 V
Voltage range at EN	–0.3 V to 6 V
Maximum PG voltage (fixed options only)	6 V
Peak output current	Internally limited
Continuous total power dissipation	See Dissipation Rating Tables
Output voltage, V_O (OUTPUT, FB)	5.5 V
Operating junction temperature range, T_J	–40°C to 150°C
Storage temperature range, T_{stg}	–65°C to 150°C
ESD rating, HBM	2 kV
ESD rating, CDM	500 V

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

[‡] All voltage values are with respect to network terminal ground.

DISSIPATION RATING TABLE

PACKAGE	$R_{\theta JC}$ (°C/W)	$R_{\theta JA}$ (°C/W) [§]
TO–220	2	58.7 [¶]
TO–263	2	38.7 [#]

[§] For both packages, the $R_{\theta JA}$ values were computed using JEDEC high K board (2S2P) with 1 ounce internal copper plane and ground plane. There was no air flow across the packages.

[¶] $R_{\theta JA}$ was computed assuming a vertical, free standing TO-220 package with pins soldered to the board. There is no heatsink attached to the package.

[#] $R_{\theta JA}$ was computed assuming a horizontally mounted TO-263 package with pins soldered to the board. There is no copper pad underneath the package.

recommended operating conditions

	MIN	MAX	UNIT
Input voltage, $V_{I }$	2.8	5.5	V
Output voltage range, V_O	1.22	5	V
Output current, I_O	0	3	A
Operating virtual junction temperature, T_J	–40	125	°C

^{||} To calculate the minimum input voltage for your maximum output current, use the following equation: $V_{I(min)} = V_{O(max)} + V_{DO(max load)}$.



TPS75715, TPS75718, TPS75725, TPS75733 WITH POWER GOOD AND TPS75701 FAST-TRANSIENT RESPONSE 3-A LOW-DROPOUT VOLTAGE REGULATORS

SLVS306E – NOVEMBER 2000 – REVISED FEBRUARY 2009

electrical characteristics over recommended operating junction temperature range ($T_J = -40^\circ\text{C}$ to 125°C), $V_I = V_{O(\text{typ})} + 1\text{ V}$, $I_O = 1\text{ mA}$, $\overline{\text{EN}} = 0\text{ V}$, $C_O = 100\text{ }\mu\text{F}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Output voltage (see Note 2)	Adjustable voltage	1.22 V ≤ V _O ≤ 5.5 V, T _J = 25°C	V _O			V
		1.22 V ≤ V _O ≤ 5.5 V	0.97 V _O	1.03 V _O		
		1.22 V ≤ V _O ≤ 5.5 V, T _J = 0 to 125°C (see Note 1)	0.98 V _O	1.02 V _O		
	1.5 V Output	T _J = 25°C, 2.8 V < V _I < 5.5 V	1.5			V
		2.8 V ≤ V _I ≤ 5.5 V	1.455	1.545		
	1.8 V Output	T _J = 25°C, 2.8 V < V _I < 5.5 V	1.8			V
		2.8 V ≤ V _I ≤ 5.5 V	1.746	1.854		
	2.5 V Output	T _J = 25°C, 3.5 V < V _I < 5.5 V	2.5			V
		3.5 V ≤ V _I ≤ 5.5 V	2.425	2.575		
	3.3 V Output	T _J = 25°C, 4.3 V < V _I < 5.5 V	3.3			V
4.3 V ≤ V _I ≤ 5.5 V		3.201	3.399			
Quiescent current (GND current) (see Notes 2 and 3)		T _J = 25°C	125			μA
			200			
Output voltage line regulation (ΔV _O /V _O) (see Note 3)		V _O + 1 V ≤ V _I ≤ 5.5 V, T _J = 25°C	0.04			%V
		V _O + 1 V ≤ V _I < 5.5 V	0.1			
Load regulation (see Note 2)			0.35			%V
Output noise voltage	TPS75715	BW = 300 Hz to 50 kHz, T _J = 25°C, V _I = 2.8 V	35			μVrms
Output current limit		V _O = 0 V	5.5	10	14	A
Thermal shutdown junction temperature			150			°C
Standby current		$\overline{\text{EN}}$ = V _I , T _J = 25°C	0.1			μA
		$\overline{\text{EN}}$ = V _I	10			μA
FB input current	TPS75701	FB = 1.5 V	-1		1	μA
Power supply ripple rejection	TPS75715	f = 100 Hz, T _J = 25°C, V _I = 2.8 V, I _O = 3 A	62			dB
Minimum input voltage for valid $\overline{\text{PG}}$		I _O (PG) = 300 μA, V(PG) ≤ 0.8 V	0			V
$\overline{\text{PG}}$ trip threshold voltage	Fixed options only	V _O decreasing	89		93	%V _O
$\overline{\text{PG}}$ hysteresis voltage	Fixed options only	Measured at V _O	0.5			%V _O
$\overline{\text{PG}}$ output low voltage	Fixed options only	V _I = 2.8 V, I _O (PG) = 1 mA	0.15		0.4	V
$\overline{\text{PG}}$ leakage current	Fixed options only	V(PG) = 5 V	1			μA

NOTES: 1. The adjustable option operates with a 2% tolerance over $T_J = 0$ to 125°C .

2. $I_O = 1\text{ mA}$ to 3 A

3. If $V_O \leq 2.5\text{ V}$ then $V_{I\text{min}} = 2.8\text{ V}$, $V_{I\text{max}} = 5.5\text{ V}$:

$$\text{Line regulation (mV)} = (\%/V) \times \frac{V_O(V_{I\text{max}} - 2.8\text{ V})}{100} \times 1000$$

If $V_O > 2.5\text{ V}$ then $V_{I\text{min}} = V_O + 1\text{ V}$, $V_{I\text{max}} = 5.5\text{ V}$:

$$\text{Line regulation (mV)} = (\%/V) \times \frac{V_O(V_{I\text{max}} - (V_O + 1\text{ V}))}{100} \times 1000$$



TPS75715, TPS75718, TPS75725, TPS75733 WITH POWER GOOD AND TPS75701 FAST-TRANSIENT RESPONSE 3-A LOW-DROPOUT VOLTAGE REGULATORS

SLVS306E – NOVEMBER 2000 – REVISED FEBRUARY 2009

electrical characteristics over recommended operating junction temperature range ($T_J = -40^{\circ}\text{C}$ to 125°C), $V_I = V_{O(\text{typ})} + 1\text{ V}$, $I_O = 1\text{ mA}$, $\overline{\text{EN}} = 0\text{ V}$, $C_O = 100\text{ }\mu\text{F}$ (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
Input current ($\overline{\text{EN}}$)		$\overline{\text{EN}} = V_I$			-1		1	μA
		$\overline{\text{EN}} = 0\text{ V}$			-1	0	1	μA
High level $\overline{\text{EN}}$ input voltage					2			V
Low level $\overline{\text{EN}}$ input voltage							0.7	V
V_O	Dropout voltage, (3.3 V output) (see Note 4)	$I_O = 3\text{ A}, \quad V_I = 3.2\text{ V}, \quad T_J = 25^\circ\text{C}$			150			mV
		$I_O = 3\text{ A}, \quad V_I = 3.2\text{ V}$			300			
	Discharge transistor current	$V_O = 1.5\text{ V}, \quad T_J = 25^\circ\text{C}$			10	25		mA
V_I	UVLO	$T_J = 25^\circ\text{C}, \quad V_I \text{ rising}$			2.2		2.75	V
	UVLO hysteresis	$T_J = 25^\circ\text{C}, \quad V_I \text{ falling}$				100		mV

NOTE 4: IN voltage equals $V_{O(\text{typ})} - 100\text{ mV}$; TPS75715, TPS75718, and TPS75725 dropout voltage limited by input voltage range limitations (i.e., TPS75733 input voltage is set to 3.2 V for the purpose of this test).

TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
V_O	Output voltage	vs Output current	2, 3
		vs Junction temperature	4, 5
	Ground current	vs Junction temperature	6
	Power supply ripple rejection	vs Frequency	7
	Output spectral noise density	vs Frequency	8
z_O	Output impedance	vs Frequency	9
V_{DO}	Dropout voltage	vs Input voltage	10
		vs Junction temperature	11
V_I	Minimum required input voltage	vs Output voltage	12
	Line transient response		13, 15
	Load transient response		14, 16
V_O	Output voltage and enable voltage	vs Time (start-up)	17
	Equivalent series resistance	vs Output current	19, 20



TPS75715, TPS75718, TPS75725, TPS75733 WITH POWER GOOD AND TPS75701 FAST-TRANSIENT RESPONSE 3-A LOW-DROPOUT VOLTAGE REGULATORS

SLVS306E – NOVEMBER 2000 – REVISED FEBRUARY 2009

TYPICAL CHARACTERISTICS

TPS75733
OUTPUT VOLTAGE
VS
OUTPUT CURRENT

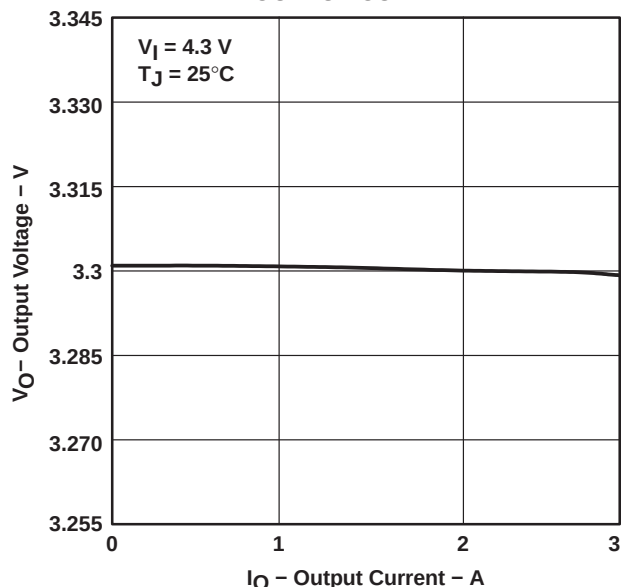


Figure 2

TPS75715
OUTPUT VOLTAGE
VS
OUTPUT CURRENT

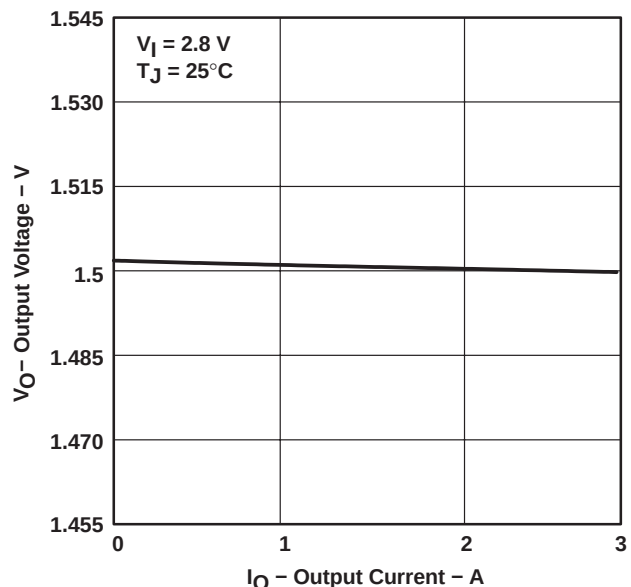


Figure 3

TPS75733
OUTPUT VOLTAGE
VS
JUNCTION TEMPERATURE

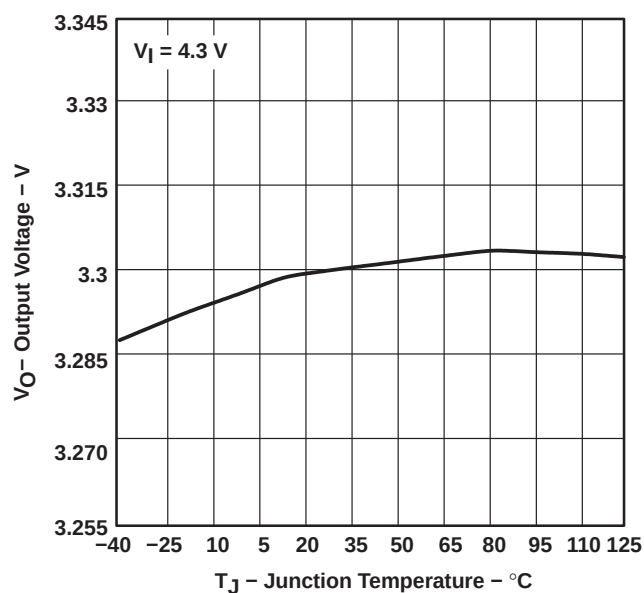


Figure 4

TPS75715
OUTPUT VOLTAGE
VS
JUNCTION TEMPERATURE

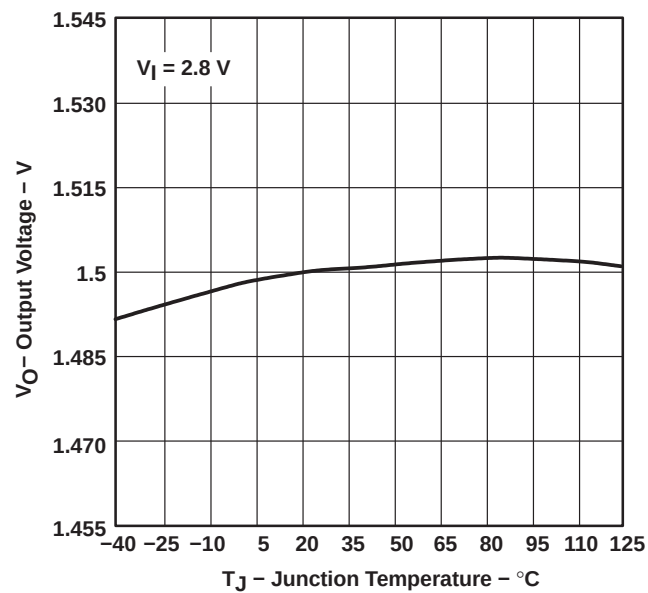


Figure 5

TPS75715, TPS75718, TPS75725, TPS75733 WITH POWER GOOD AND TPS75701 FAST-TRANSIENT RESPONSE 3-A LOW-DROPOUT VOLTAGE REGULATORS

SLVS306E – NOVEMBER 2000 – REVISED FEBRUARY 2009

TYPICAL CHARACTERISTICS

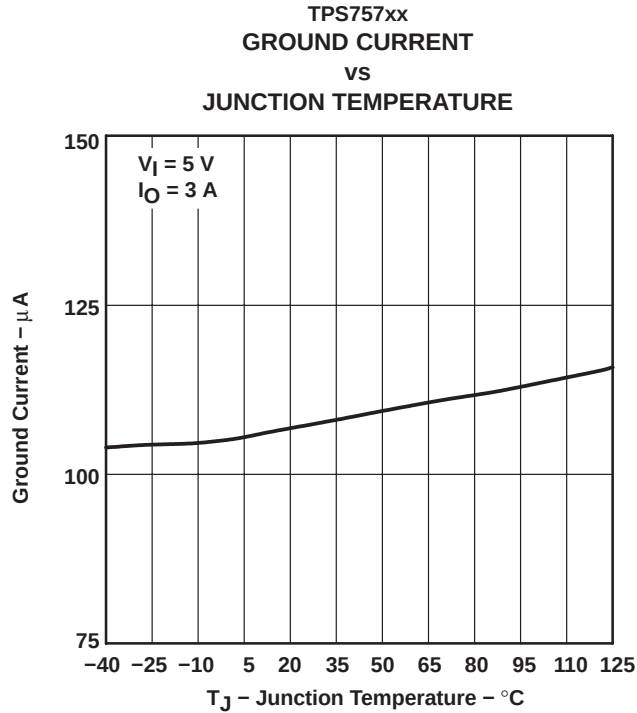


Figure 6

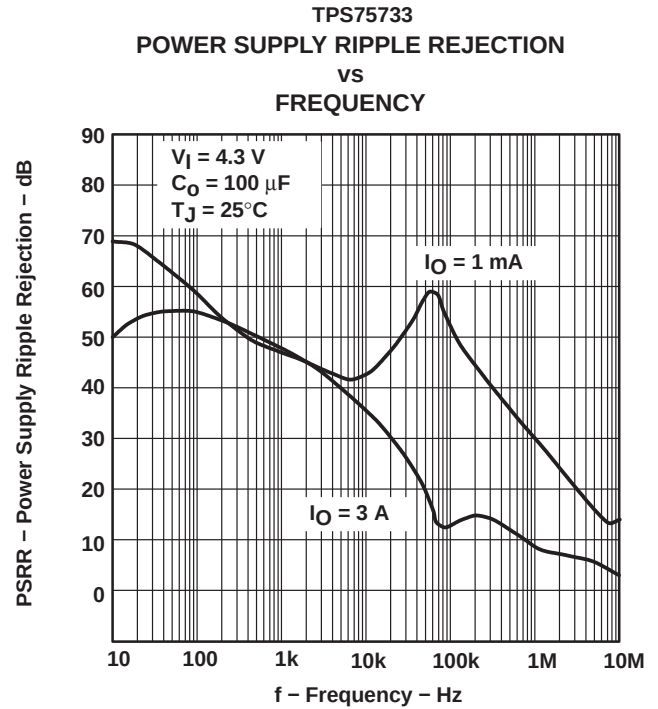


Figure 7

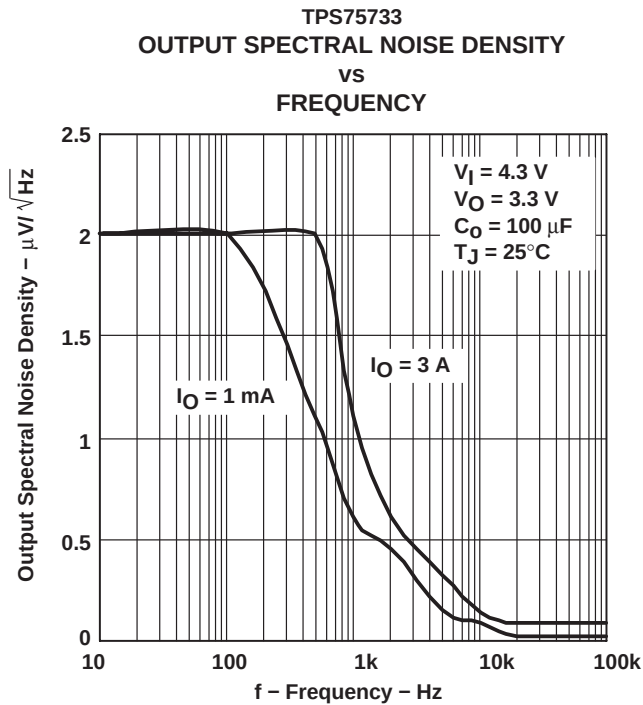


Figure 8

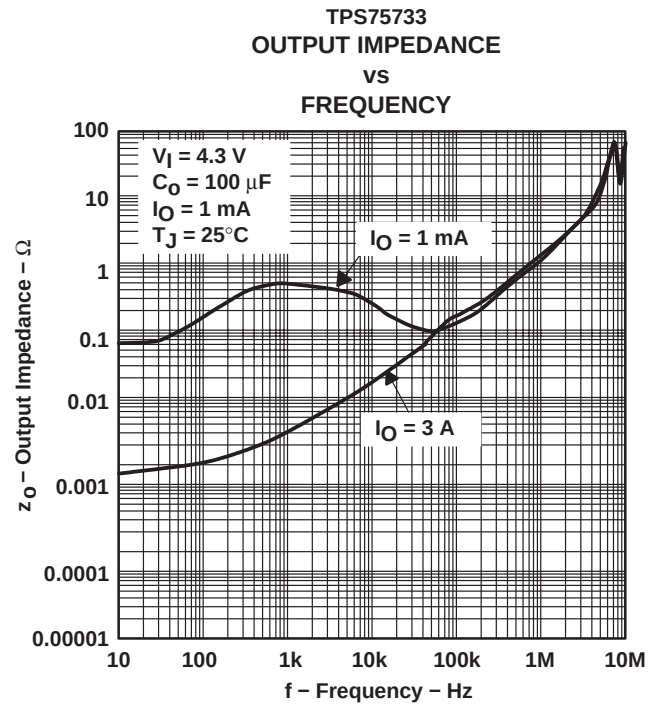


Figure 9

TPS75715, TPS75718, TPS75725, TPS75733 WITH POWER GOOD AND TPS75701 FAST-TRANSIENT RESPONSE 3-A LOW-DROPOUT VOLTAGE REGULATORS

SLVS306E – NOVEMBER 2000 – REVISED FEBRUARY 2009

TYPICAL CHARACTERISTICS

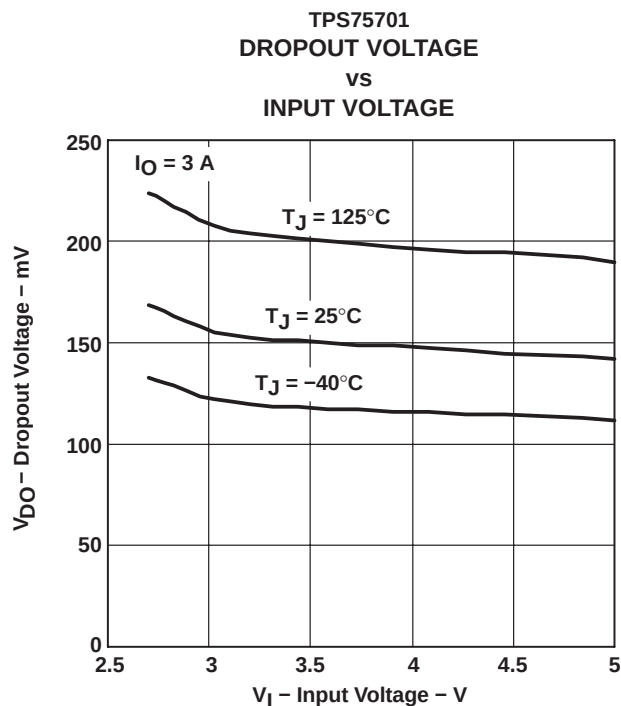


Figure 10

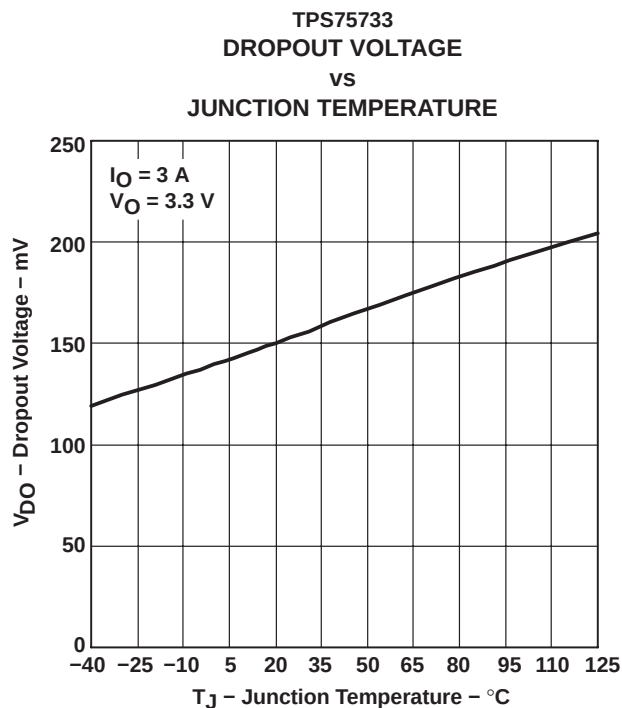


Figure 11

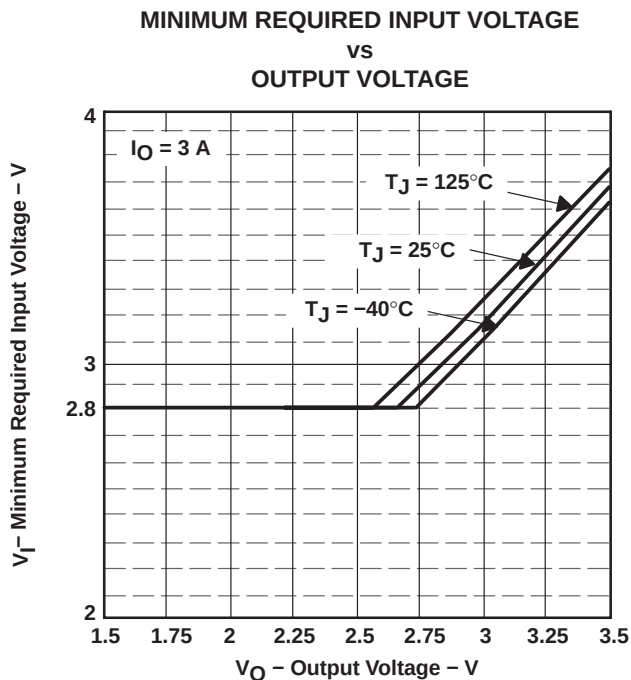


Figure 12

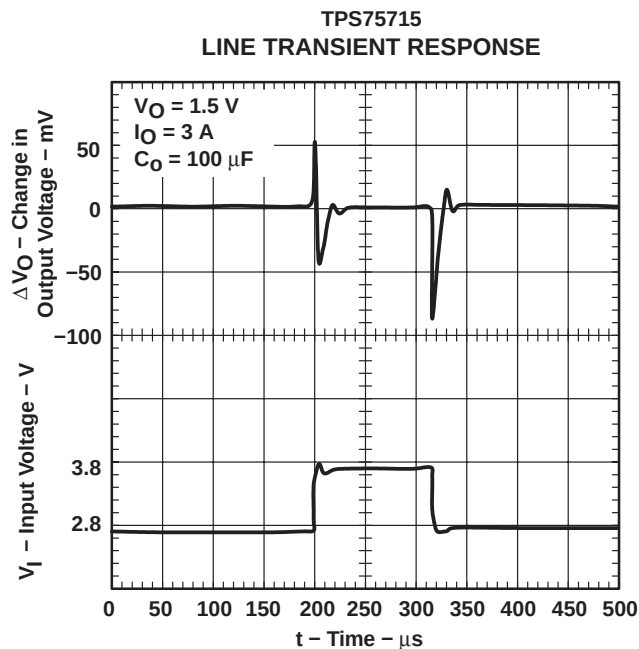


Figure 13

TPS75715, TPS75718, TPS75725, TPS75733 WITH POWER GOOD AND TPS75701 FAST-TRANSIENT RESPONSE 3-A LOW-DROPOUT VOLTAGE REGULATORS

SLVS306E – NOVEMBER 2000 – REVISED FEBRUARY 2009

TYPICAL CHARACTERISTICS

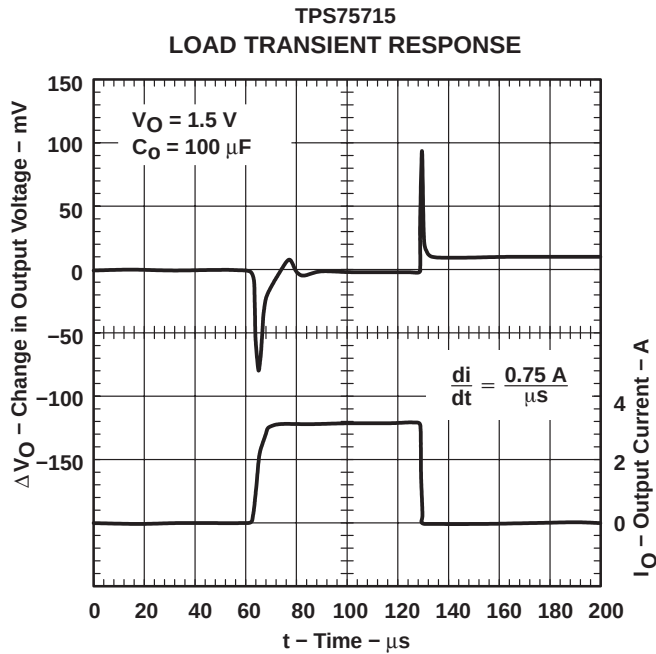


Figure 14

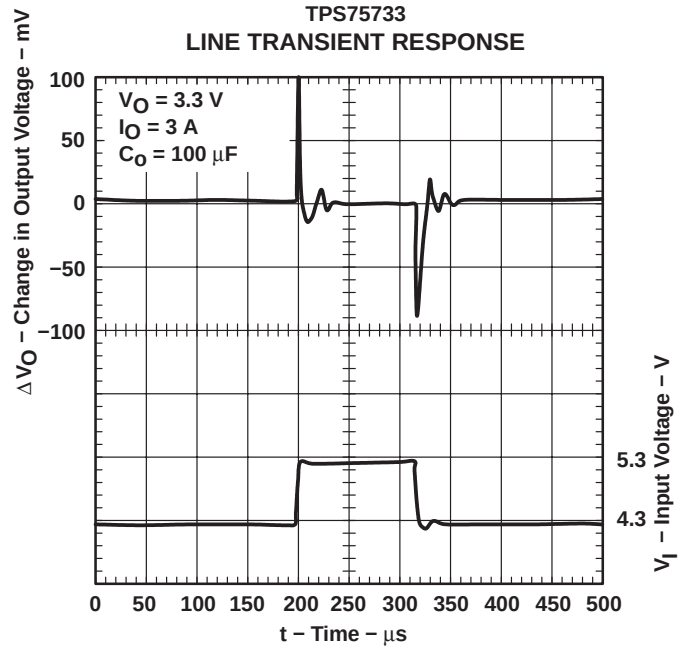


Figure 15

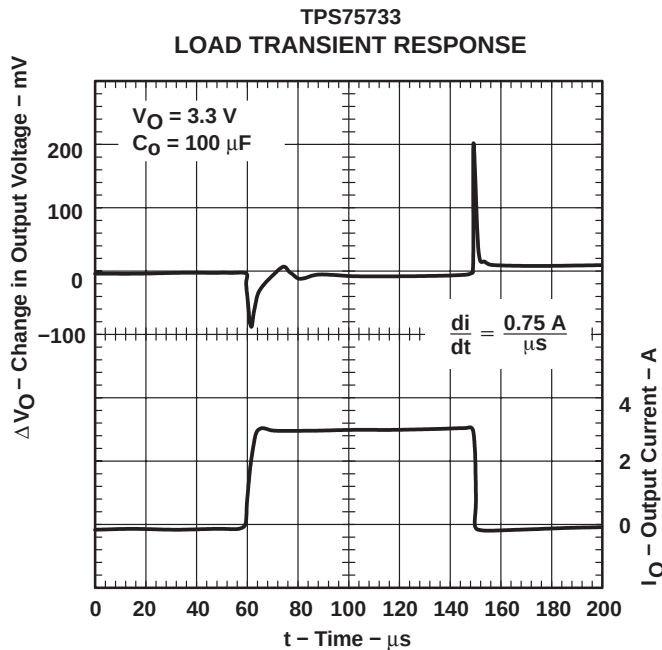


Figure 16

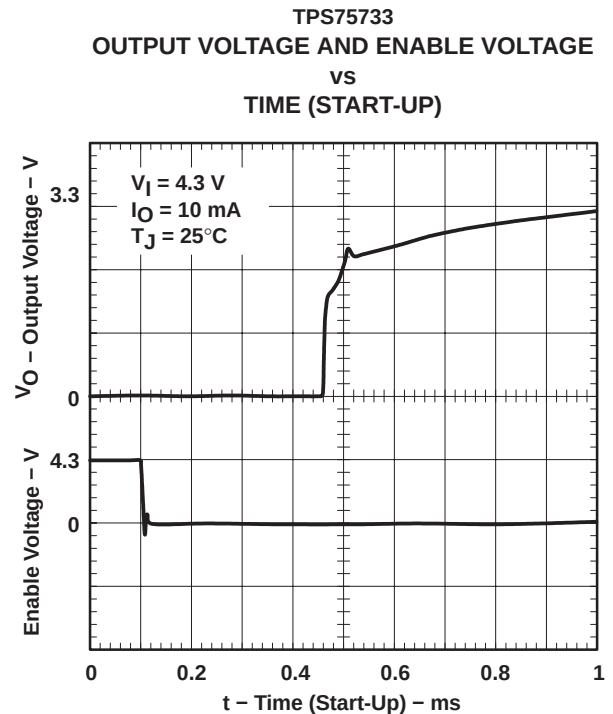


Figure 17

TPS75715, TPS75718, TPS75725, TPS75733 WITH POWER GOOD AND
TPS75701 FAST-TRANSIENT RESPONSE 3-A LOW-DROPOUT
VOLTAGE REGULATORS

SLVS306E – NOVEMBER 2000 – REVISED FEBRUARY 2009

TYPICAL CHARACTERISTICS

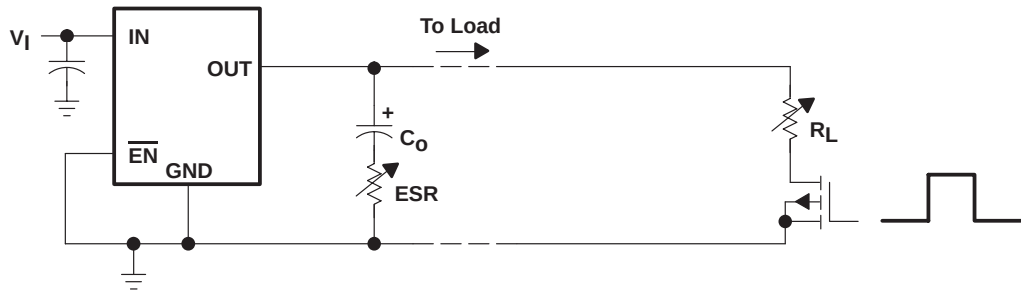


Figure 18. Test Circuit for Typical Regions of Stability (Figures 19 and 20) (Fixed Output Options)

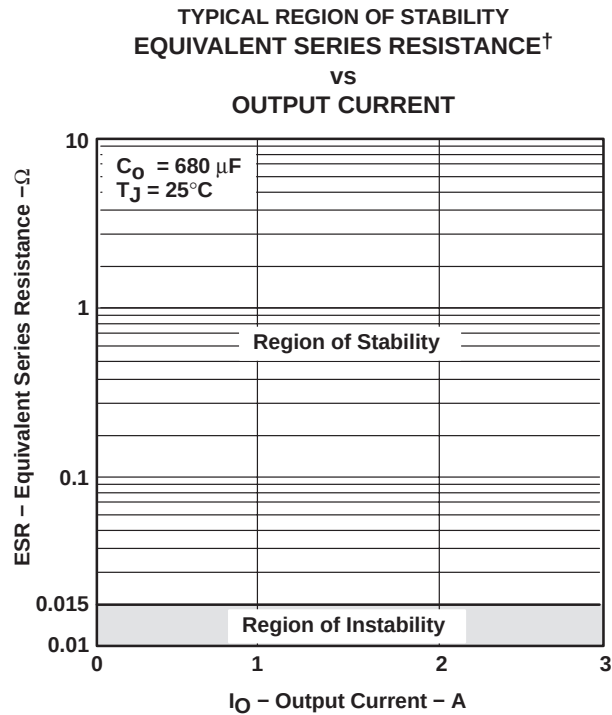


Figure 19

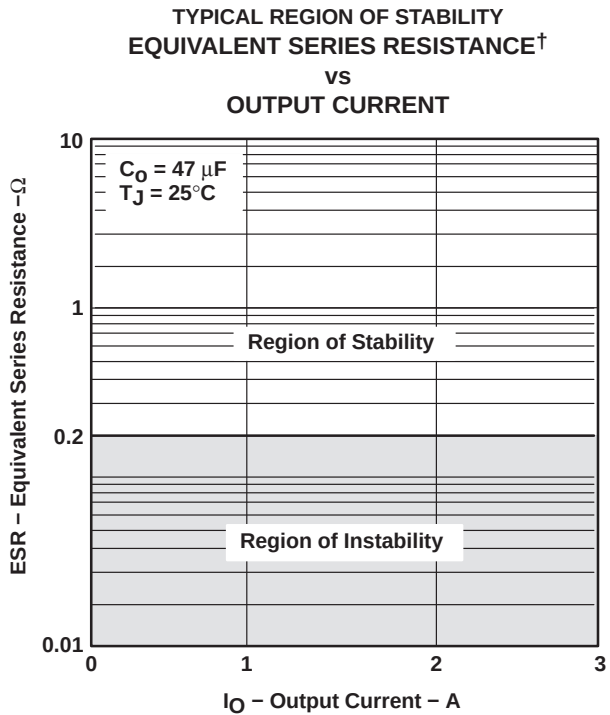


Figure 20

[†] Equivalent series resistance (ESR) refers to the total series resistance, including the ESR of the capacitor, any series resistance added externally, and PWB trace resistance to C_O .

THERMAL INFORMATION

The amount of heat that an LDO linear regulator generates is directly proportional to the amount of power it dissipates during operation. All integrated circuits have a maximum allowable junction temperature (T_{Jmax}) above which normal operation is not assured. A system designer must design the operating environment so that the operating junction temperature (T_J) does not exceed the maximum junction temperature (T_{Jmax}). The two main environmental variables that a designer can use to improve thermal performance are air flow and external heatsinks. The purpose of this information is to aid the designer in determining the proper operating environment for a linear regulator that is operating at a specific power level.

In general, the maximum expected power ($P_{D(max)}$) consumed by a linear regulator is computed as:

$$P_{Dmax} = (V_{I(avg)} - V_{O(avg)}) \times I_{O(avg)} + V_{I(avg)} \times I_{(Q)} \quad (1)$$

Where:

$V_{I(avg)}$ is the average input voltage.

$V_{O(avg)}$ is the average output voltage.

$I_{O(avg)}$ is the average output current.

$I_{(Q)}$ is the quiescent current.

For most TI LDO regulators, the quiescent current is insignificant compared to the average output current; therefore, the term $V_{I(avg)} \times I_{(Q)}$ can be neglected. The operating junction temperature is computed by adding the ambient temperature (T_A) and the increase in temperature due to the regulator's power dissipation. The temperature rise is computed by multiplying the maximum expected power dissipation by the sum of the thermal resistances between the junction and the case ($R_{\theta JC}$), the case to heatsink ($R_{\theta CS}$), and the heatsink to ambient ($R_{\theta SA}$). Thermal resistances are measures of how effectively an object dissipates heat. Typically, the larger the device, the more surface area available for power dissipation and the lower the object's thermal resistance.

Figure 21 illustrates these thermal resistances for (a) a TO-220 package attached to a heatsink, and (b) a TO-263 package mounted on a JEDEC High-K board.

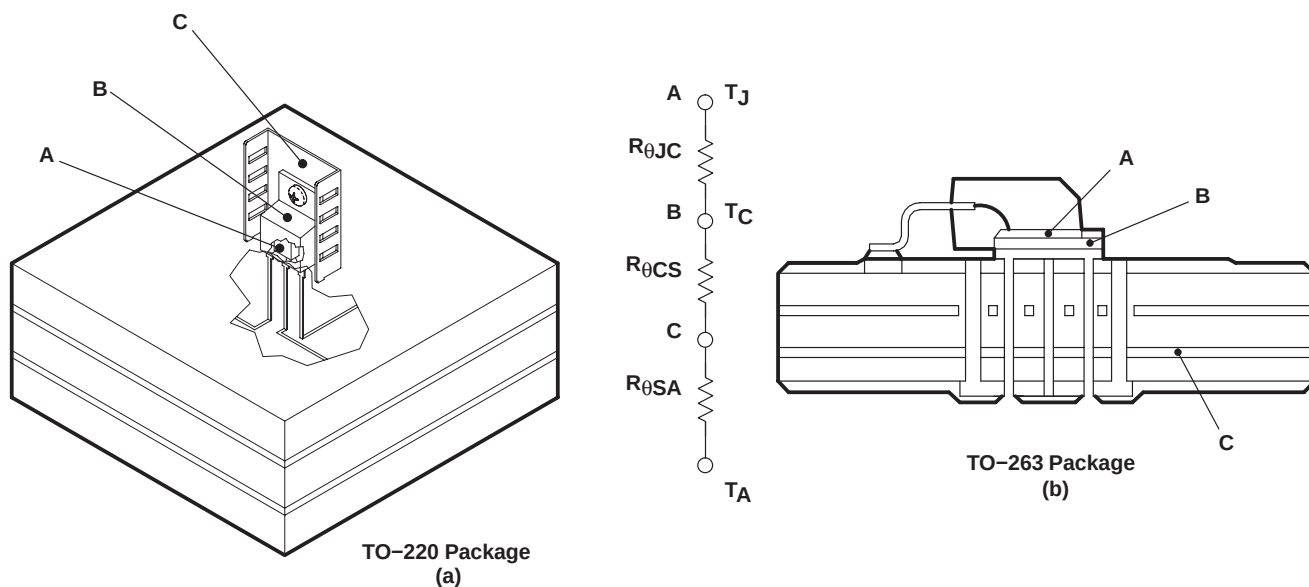


Figure 21. Thermal Resistances

TPS75715, TPS75718, TPS75725, TPS75733 WITH POWER GOOD AND TPS75701 FAST-TRANSIENT RESPONSE 3-A LOW-DROPOUT VOLTAGE REGULATORS

SLVS306E – NOVEMBER 2000 – REVISED FEBRUARY 2009

THERMAL INFORMATION

Equation 2 summarizes the computation:

$$T_J = T_A + P_{D\max} \times (R_{\theta JC} + R_{\theta CS} + R_{\theta SA}) \quad (2)$$

The $R_{\theta JC}$ is specific to each regulator as determined by its package, lead frame, and die size provided in the regulator's datasheet. The $R_{\theta SA}$ is a function of the type and size of heatsink. For example, *black body radiator* type heatsinks, like the one attached to the TO-220 package in Figure 21(a), can have $R_{\theta CS}$ values ranging from 5°C/W for very large heatsinks to 50°C/W for very small heatsinks. The $R_{\theta CS}$ is a function of how the package is attached to the heatsink. For example, if a thermal compound is used to attach a heatsink to a TO-220 package, $R_{\theta CS}$ of 1°C/W is reasonable.

Even if no external *black body radiator* type heatsink is attached to the package, the board on which the regulator is mounted will provide some heatsinking through the pin solder connections. Some packages, like the TO-263 and TI's TSSOP PowerPAD™ packages, use a copper plane underneath the package or the circuit board's ground plane for additional heatsinking to improve their thermal performance. Computer aided thermal modeling can be used to compute very accurate approximations of an integrated circuit's thermal performance in different operating environments (e.g., different types of circuit boards, different types and sizes of heatsinks, and different air flows, etc.). Using these models, the three thermal resistances can be combined into one thermal resistance between junction and ambient ($R_{\theta JA}$). This $R_{\theta JA}$ is valid only for the specific operating environment used in the computer model.

Equation 2 simplifies into equation 3:

$$T_J = T_A + P_{D\max} \times R_{\theta JA} \quad (3)$$

Rearranging equation 3 gives equation 4:

$$R_{\theta JA} = \frac{T_J - T_A}{P_{D\max}} \quad (4)$$

Using equation 3 and the computer model generated curves shown in Figures 22 and 25, a designer can quickly compute the required heatsink thermal resistance/board area for a given ambient temperature, power dissipation, and operating environment.

THERMAL INFORMATION

TO–220 power dissipation

The TO–220 package provides an effective means of managing power dissipation in through-hole applications. The TO–220 package dimensions are provided in the *Mechanical Data* section at the end of the data sheet. A heatsink can be used with the TO–220 package to effectively lower the junction-to-ambient thermal resistance.

To illustrate, the TPS75725 in a TO–220 package was chosen. For this example, the average input voltage is 3.3 V, the output voltage is 2.5 V, the average output current is 3 A, the ambient temperature 55°C, the air flow is 150 LFM, and the operating environment is the same as documented below. Neglecting the quiescent current, the maximum average power is:

$$P_{D\max} = (3.3 - 2.5) \text{ V} \times 3 \text{ A} = 2.4 \text{ W} \quad (5)$$

Substituting $T_{J\max}$ for T_J into equation 4 gives equation 6:

$$R_{\theta JA\max} = (125 - 55)^\circ\text{C} / 2.4 \text{ W} = 29^\circ\text{C/W} \quad (6)$$

From Figure 22, $R_{\theta JA}$ vs Heatsink Thermal Resistance, a heatsink with $R_{\theta SA} = 22^\circ\text{C/W}$ is required to dissipate 2.4 W. The model operating environment used in the computer model to construct Figure 22 consisted of a standard JEDEC High-K board (2S2P) with a 1 oz. internal copper plane and ground plane. Since the package pins were soldered to the board, 450 mm² of the board was modeled as a heatsink. Figure 23 shows the side view of the operating environment used in the computer model.

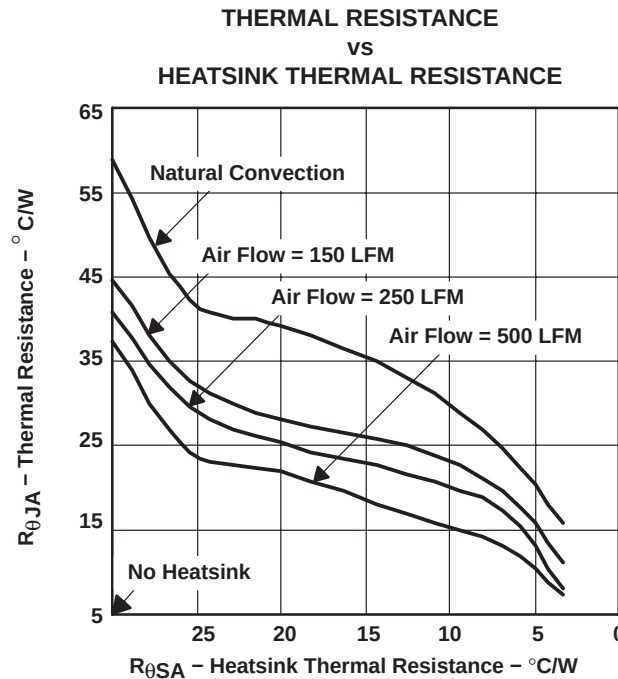


Figure 22

TPS75715, TPS75718, TPS75725, TPS75733 WITH POWER GOOD AND TPS75701 FAST-TRANSIENT RESPONSE 3-A LOW-DROPOUT VOLTAGE REGULATORS

SLVS306E – NOVEMBER 2000 – REVISED FEBRUARY 2009

THERMAL INFORMATION

TO-220 power dissipation (continued)

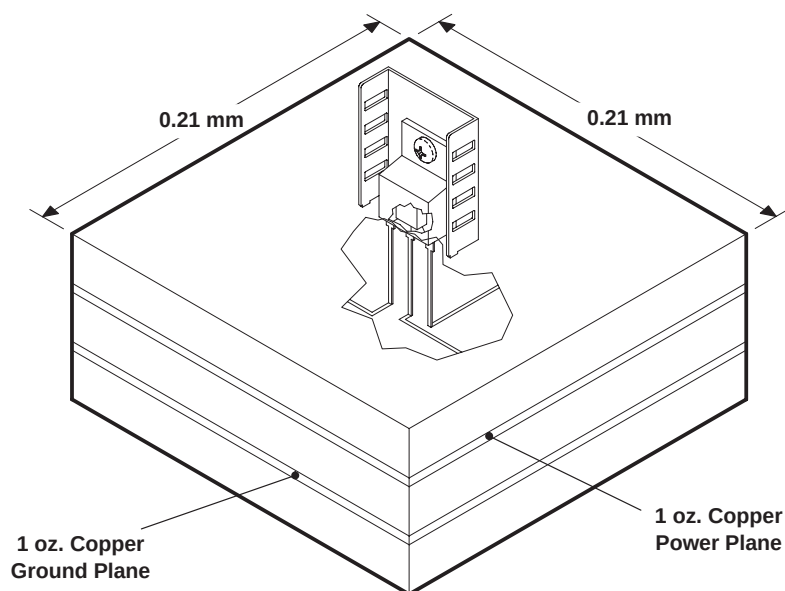


Figure 23

From the data in Figure 22 and rearranging equation 4, the maximum power dissipation for a different heatsink $R_{\theta SA}$ and a specific ambient temperature can be computed (see Figure 24).

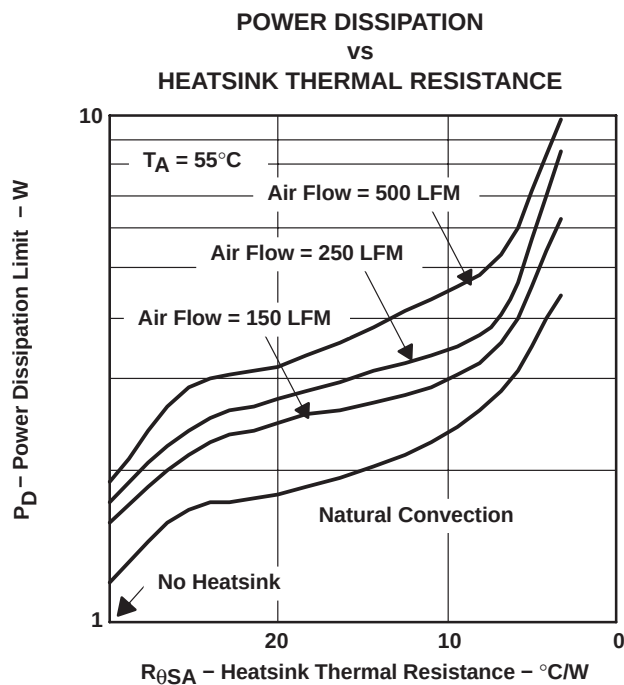


Figure 24

THERMAL INFORMATION

TO-263 power dissipation

The TO-263 package provides an effective means of managing power dissipation in surface mount applications. The TO-263 package dimensions are provided in the *Mechanical Data* section at the end of the data sheet. The addition of a copper plane directly underneath the TO-263 package enhances the thermal performance of the package.

To illustrate, the TPS75725 in a TO-263 package was chosen. For this example, the average input voltage is 3.3 V, the output voltage is 2.5 V, the average output current is 3 A, the ambient temperature 55°C, the air flow is 150 LFM, and the operating environment is the same as documented below. Neglecting the quiescent current, the maximum average power is:

$$P_{Dmax} = (3.3 - 2.5) V \times 3 A = 2.4 W \quad (7)$$

Substituting T_{Jmax} for T_J into equation 4 gives equation 8:

$$R_{\theta JAmax} = (125 - 55)^{\circ}C / 2.4 W = 29^{\circ}C/W \quad (8)$$

From Figure 25, $R_{\theta JA}$ vs Copper Heatsink Area, the ground plane needs to be 2 cm² for the part to dissipate 2.4 W. The model operating environment used in the computer model to construct Figure 25 consisted of a standard JEDEC High-K board (2S2P) with a 1 oz. internal copper plane and ground plane. The package is soldered to a 2 oz. copper pad. The pad is tied through thermal vias to the 1 oz. ground plane. Figure 26 shows the side view of the operating environment used in the computer model.

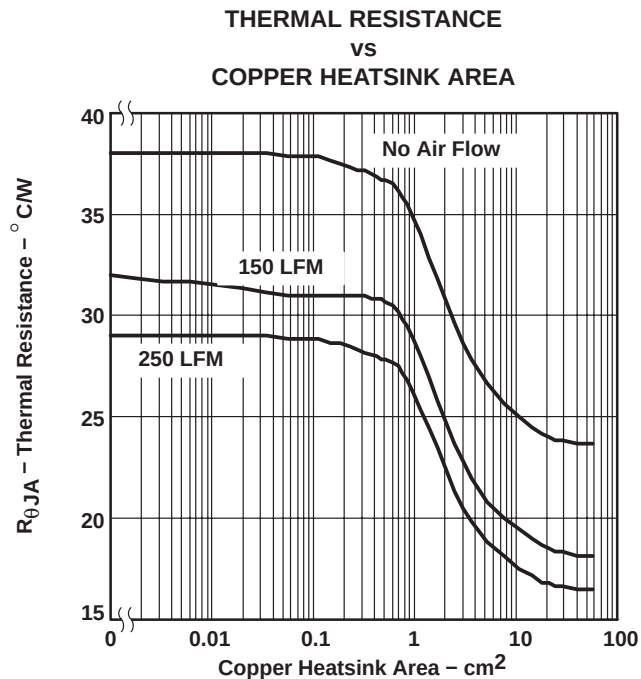


Figure 25

TPS75715, TPS75718, TPS75725, TPS75733 WITH POWER GOOD AND TPS75701 FAST-TRANSIENT RESPONSE 3-A LOW-DROPOUT VOLTAGE REGULATORS

SLVS306E – NOVEMBER 2000 – REVISED FEBRUARY 2009

THERMAL INFORMATION

TO-263 power dissipation (continued)

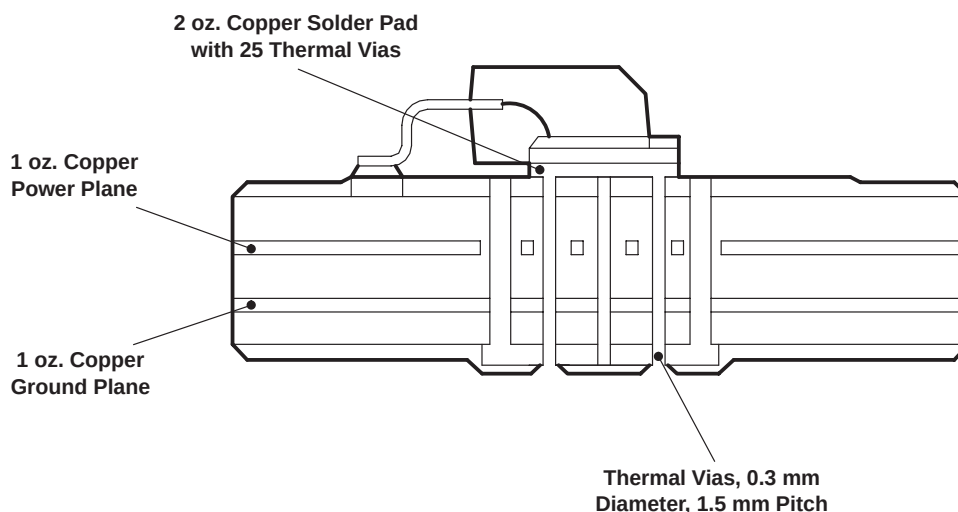


Figure 26

From the data in Figure 25 and rearranging equation 4, the maximum power dissipation for a different ground plane area and a specific ambient temperature can be computed (see Figure 27).

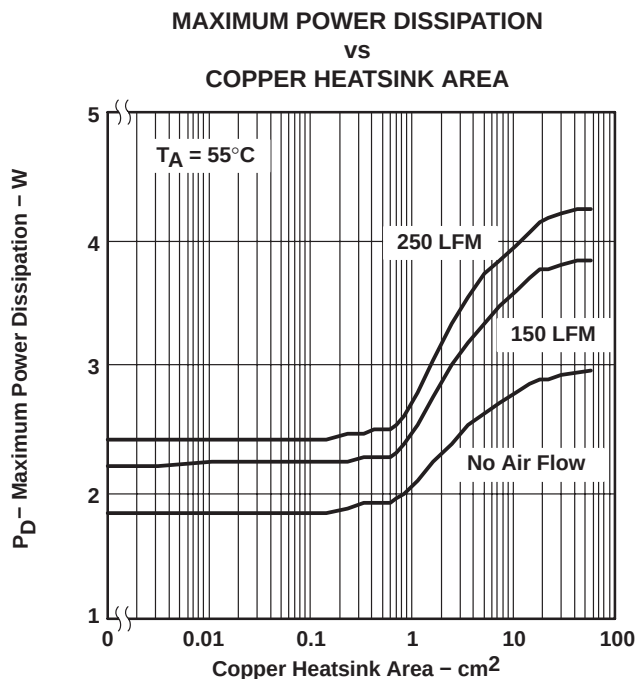


Figure 27

APPLICATION INFORMATION

programming the TPS75701 adjustable LDO regulator

The output voltage of the TPS75701 adjustable regulator is programmed using an external resistor divider as shown in Figure 28. The output voltage is calculated using:

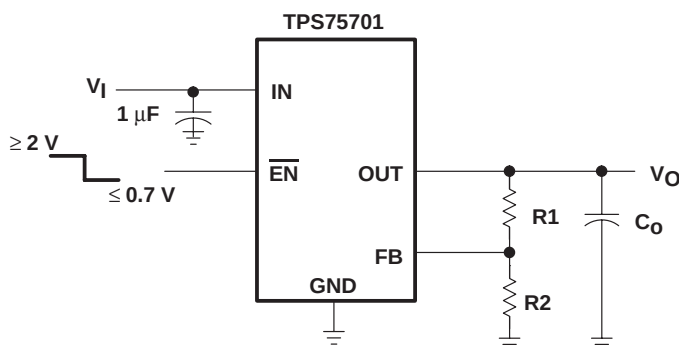
$$V_O = V_{\text{ref}} \times \left(1 + \frac{R_1}{R_2}\right) \quad (9)$$

Where:

$$V_{\text{ref}} = 1.224 \text{ V typ (the internal reference voltage)}$$

Resistors R1 and R2 should be chosen for approximately 40-μA divider current. Lower value resistors can be used but offer no inherent advantage and waste more power. Higher values should be avoided as leakage currents at FB increase the output voltage error. The recommended design procedure is to choose R2 = 30.1 kΩ to set the divider current at 40 μA and then calculate R1 using:

$$R_1 = \left(\frac{V_O}{V_{\text{ref}}} - 1\right) \times R_2 \quad (10)$$



**OUTPUT VOLTAGE
PROGRAMMING GUIDE**

OUTPUT VOLTAGE	R1	R2	UNIT
2.5 V	31.4	30.1	kΩ
3.3 V	51	30.1	kΩ
3.6 V	58.3	30.1	kΩ

Figure 28. TPS75701 Adjustable LDO Regulator Programming

regulator protection

The TPS757xx PMOS-pass transistor has a built-in back diode that conducts reverse currents when the input voltage drops below the output voltage (e.g., during power down). Current is conducted from the output to the input and is not internally limited. When extended reverse voltage is anticipated, external limiting may be appropriate.

The TPS757xx also features internal current limiting and thermal protection. During normal operation, the TPS757xx limits output current to approximately 10 A. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. While current limiting is designed to prevent gross device failure, care should be taken not to exceed the power dissipation ratings of the package. If the temperature of the device exceeds 150°C(typ), thermal-protection circuitry shuts it down. Once the device has cooled below 130°C(typ), regulator operation resumes.

TPS75715, TPS75718, TPS75725, TPS75733 WITH POWER GOOD AND TPS75701 FAST-TRANSIENT RESPONSE 3-A LOW-DROPOUT VOLTAGE REGULATORS

SLVS306E – NOVEMBER 2000 – REVISED FEBRUARY 2009

APPLICATION INFORMATION

input capacitor

For a typical application, a ceramic input bypass capacitor ($0.22\ \mu\text{F}$ – $1\ \mu\text{F}$) is recommended to ensure device stability. This capacitor should be as close as possible to the input pin. Due to the impedance of the input supply, large transient currents will cause the input voltage to droop. If this droop causes the input voltage to drop below the UVLO threshold, the device will turn off. Therefore, it is recommended that a larger capacitor be placed in parallel with the ceramic bypass capacitor at the regulator's input. The size of this capacitor depends on the output current, response time of the main power supply, and the main power supply's distance to the regulator. At a minimum, the capacitor should be sized to ensure that the input voltage does not drop below the minimum UVLO threshold voltage during normal operating conditions.

output capacitor

As with most LDO regulators, the TPS757xx requires an output capacitor connected between OUT and GND to stabilize the internal control loop. The minimum recommended capacitance value is $47\ \mu\text{F}$ with an ESR (equivalent series resistance) of at least $200\ \text{m}\Omega$. As shown in Figure 29, most capacitor and ESR combinations with a product of $47\text{e-}6 \times 0.2 = 9.4\text{e-}6$ or larger will be stable, provided the capacitor value is at least $47\ \mu\text{F}$. Solid tantalum electrolytic and aluminum electrolytic capacitors are all suitable, provided they meet the requirements described in this section. Larger capacitors provide a wider range of stability and better load transient response.

This information along with the ESR graphs, Figures 19, 20, and 29, is included to assist in selection of suitable capacitance for the user's application. When necessary to achieve low height requirements along with high output current and/or high load capacitance, several higher ESR capacitors can be used in parallel to meet these guidelines.

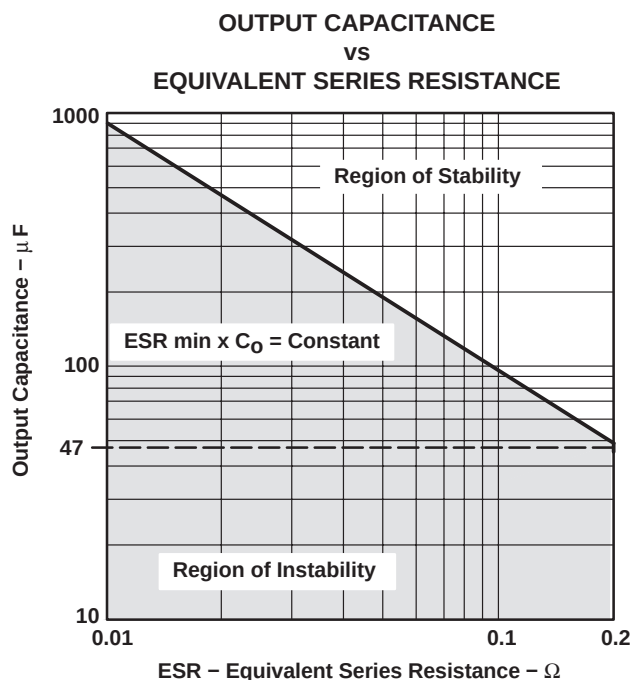


Figure 29

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TPS75701KC	ACTIVE	TO-220	KC	5	50	Green (RoHS & no Sb/Br)	CU SN	N / A for Pkg Type
TPS75701KCG3	ACTIVE	TO-220	KC	5	50	Green (RoHS & no Sb/Br)	CU SN	N / A for Pkg Type
TPS75701KTT	OBSOLETE	DDPAK/ TO-263	KTT	5		TBD	Call TI	Call TI
TPS75701KTTR	ACTIVE	DDPAK/ TO-263	KTT	5	500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR
TPS75701KTTRG3	ACTIVE	DDPAK/ TO-263	KTT	5	500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR
TPS75701KTTT	ACTIVE	DDPAK/ TO-263	KTT	5	50	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR
TPS75701KTTTG3	ACTIVE	DDPAK/ TO-263	KTT	5	50	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR
TPS75715KC	ACTIVE	TO-220	KC	5	50	Green (RoHS & no Sb/Br)	CU SN	N / A for Pkg Type
TPS75715KCG3	ACTIVE	TO-220	KC	5	50	Green (RoHS & no Sb/Br)	CU SN	N / A for Pkg Type
TPS75715KTT	OBSOLETE	DDPAK/ TO-263	KTT	5		TBD	Call TI	Call TI
TPS75715KTTR	ACTIVE	DDPAK/ TO-263	KTT	5	500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR
TPS75715KTTRG3	ACTIVE	DDPAK/ TO-263	KTT	5	500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR
TPS75715KTTT	ACTIVE	DDPAK/ TO-263	KTT	5	50	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR
TPS75715KTTTG3	ACTIVE	DDPAK/ TO-263	KTT	5	50	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR
TPS75718KC	ACTIVE	TO-220	KC	5	50	Green (RoHS & no Sb/Br)	CU SN	N / A for Pkg Type
TPS75718KCG3	ACTIVE	TO-220	KC	5	50	Green (RoHS & no Sb/Br)	CU SN	N / A for Pkg Type
TPS75718KTT	OBSOLETE	DDPAK/ TO-263	KTT	5		TBD	Call TI	Call TI
TPS75718KTTR	ACTIVE	DDPAK/ TO-263	KTT	5	500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR
TPS75718KTTRG3	ACTIVE	DDPAK/ TO-263	KTT	5	500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR
TPS75718KTTT	ACTIVE	DDPAK/ TO-263	KTT	5	50	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR
TPS75718KTTTG3	ACTIVE	DDPAK/ TO-263	KTT	5	50	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR
TPS75725KC	ACTIVE	TO-220	KC	5	50	Green (RoHS & no Sb/Br)	CU SN	N / A for Pkg Type
TPS75725KCG3	ACTIVE	TO-220	KC	5	50	Green (RoHS & no Sb/Br)	CU SN	N / A for Pkg Type
TPS75725KTT	OBSOLETE	DDPAK/ TO-263	KTT	5		TBD	Call TI	Call TI
TPS75725KTTR	ACTIVE	DDPAK/ TO-263	KTT	5	500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TPS75725KTTRG3	ACTIVE	DDPAK/ TO-263	KTT	5	500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR
TPS75725KTTT	ACTIVE	DDPAK/ TO-263	KTT	5	50	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR
TPS75725KTTTG3	ACTIVE	DDPAK/ TO-263	KTT	5	50	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR
TPS75733KC	ACTIVE	TO-220	KC	5	50	Green (RoHS & no Sb/Br)	CU SN	N / A for Pkg Type
TPS75733KCG3	ACTIVE	TO-220	KC	5	50	Green (RoHS & no Sb/Br)	CU SN	N / A for Pkg Type
TPS75733KTT	OBSOLETE	DDPAK/ TO-263	KTT	5		TBD	Call TI	Call TI
TPS75733KTTR	ACTIVE	DDPAK/ TO-263	KTT	5	500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR
TPS75733KTTRG3	ACTIVE	DDPAK/ TO-263	KTT	5	500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR
TPS75733KTTT	ACTIVE	DDPAK/ TO-263	KTT	5	50	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR
TPS75733KTTTG3	ACTIVE	DDPAK/ TO-263	KTT	5	50	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

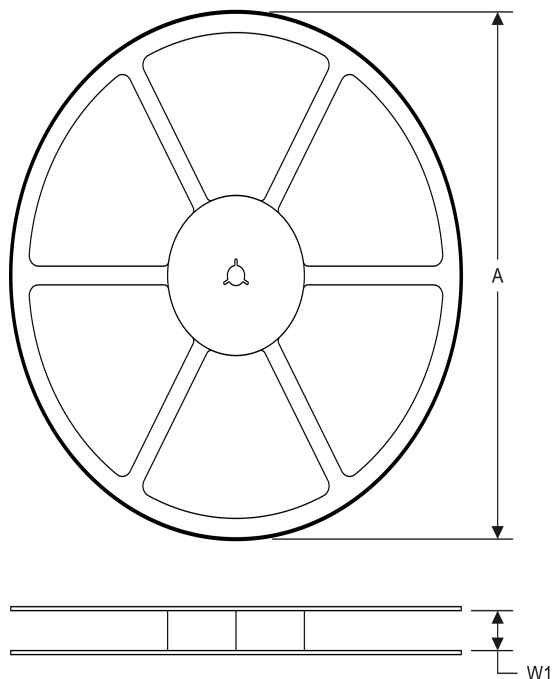
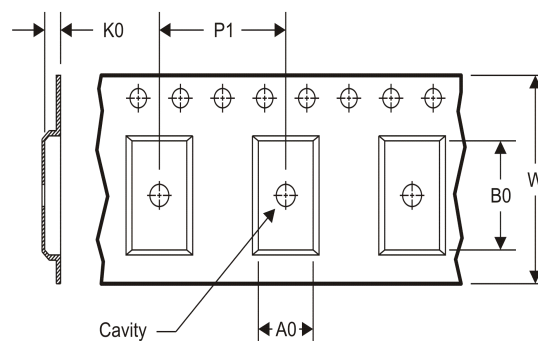
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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TAPE AND REEL INFORMATION
REEL DIMENSIONS

TAPE DIMENSIONS


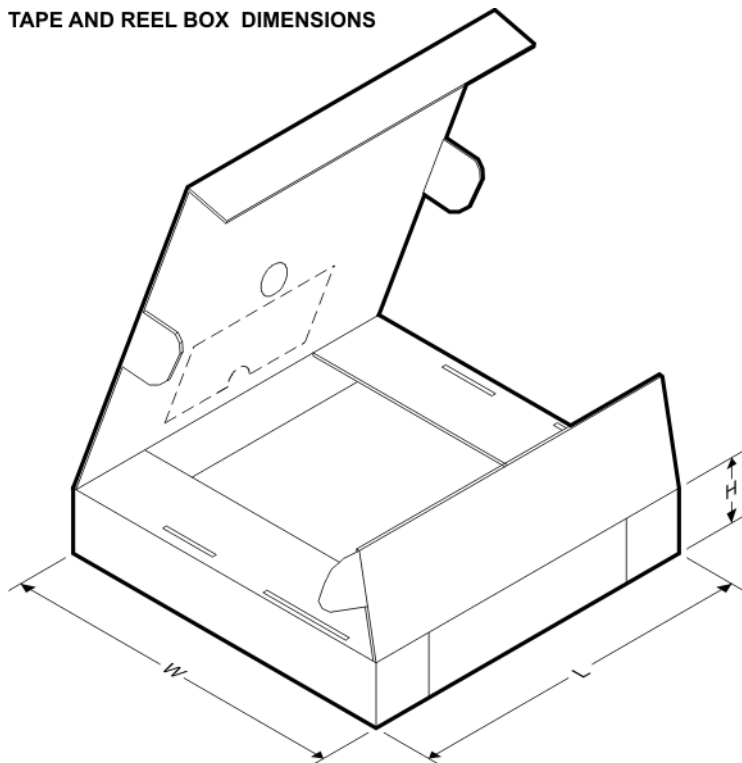
A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS75701KTTR	DDPAK/TO-263	KTT	5	500	330.0	24.4	10.6	15.6	4.9	16.0	24.0	Q2
TPS75701KTTT	DDPAK/TO-263	KTT	5	50	330.0	24.4	10.6	15.6	4.9	16.0	24.0	Q2
TPS75715KTTR	DDPAK/TO-263	KTT	5	500	330.0	24.4	10.6	15.6	4.9	16.0	24.0	Q2
TPS75715KTTT	DDPAK/TO-263	KTT	5	50	330.0	24.4	10.6	15.6	4.9	16.0	24.0	Q2
TPS75718KTTR	DDPAK/TO-263	KTT	5	500	330.0	24.4	10.6	15.6	4.9	16.0	24.0	Q2
TPS75718KTTT	DDPAK/TO-263	KTT	5	50	330.0	24.4	10.6	15.6	4.9	16.0	24.0	Q2
TPS75725KTTR	DDPAK/TO-263	KTT	5	500	330.0	24.4	10.6	15.6	4.9	16.0	24.0	Q2
TPS75725KTTT	DDPAK/TO-263	KTT	5	50	330.0	24.4	10.6	15.6	4.9	16.0	24.0	Q2
TPS75733KTTR	DDPAK/TO-263	KTT	5	500	330.0	24.4	10.6	15.6	4.9	16.0	24.0	Q2
TPS75733KTTT	DDPAK/TO-263	KTT	5	50	330.0	24.4	10.6	15.6	4.9	16.0	24.0	Q2

TAPE AND REEL BOX DIMENSIONS

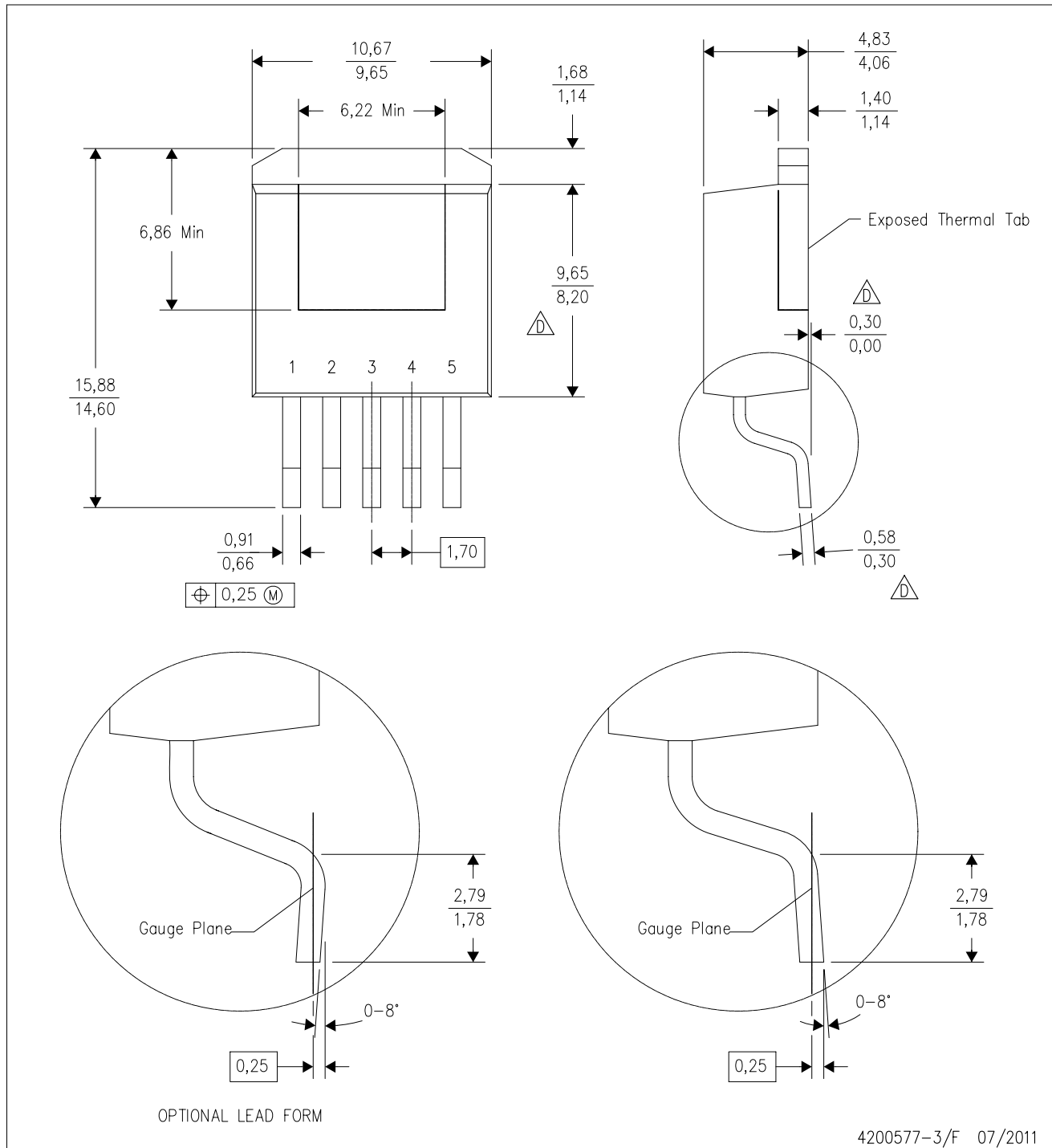


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS75701KTTR	DDPAK/TO-263	KTT	5	500	367.0	367.0	45.0
TPS75701KTTT	DDPAK/TO-263	KTT	5	50	367.0	367.0	45.0
TPS75715KTTR	DDPAK/TO-263	KTT	5	500	367.0	367.0	45.0
TPS75715KTTT	DDPAK/TO-263	KTT	5	50	367.0	367.0	45.0
TPS75718KTTR	DDPAK/TO-263	KTT	5	500	367.0	367.0	45.0
TPS75718KTTT	DDPAK/TO-263	KTT	5	50	367.0	367.0	45.0
TPS75725KTTR	DDPAK/TO-263	KTT	5	500	367.0	367.0	45.0
TPS75725KTTT	DDPAK/TO-263	KTT	5	50	367.0	367.0	45.0
TPS75733KTTR	DDPAK/TO-263	KTT	5	500	367.0	367.0	45.0
TPS75733KTTT	DDPAK/TO-263	KTT	5	50	367.0	367.0	45.0

KTT (R-PSFM-G5)

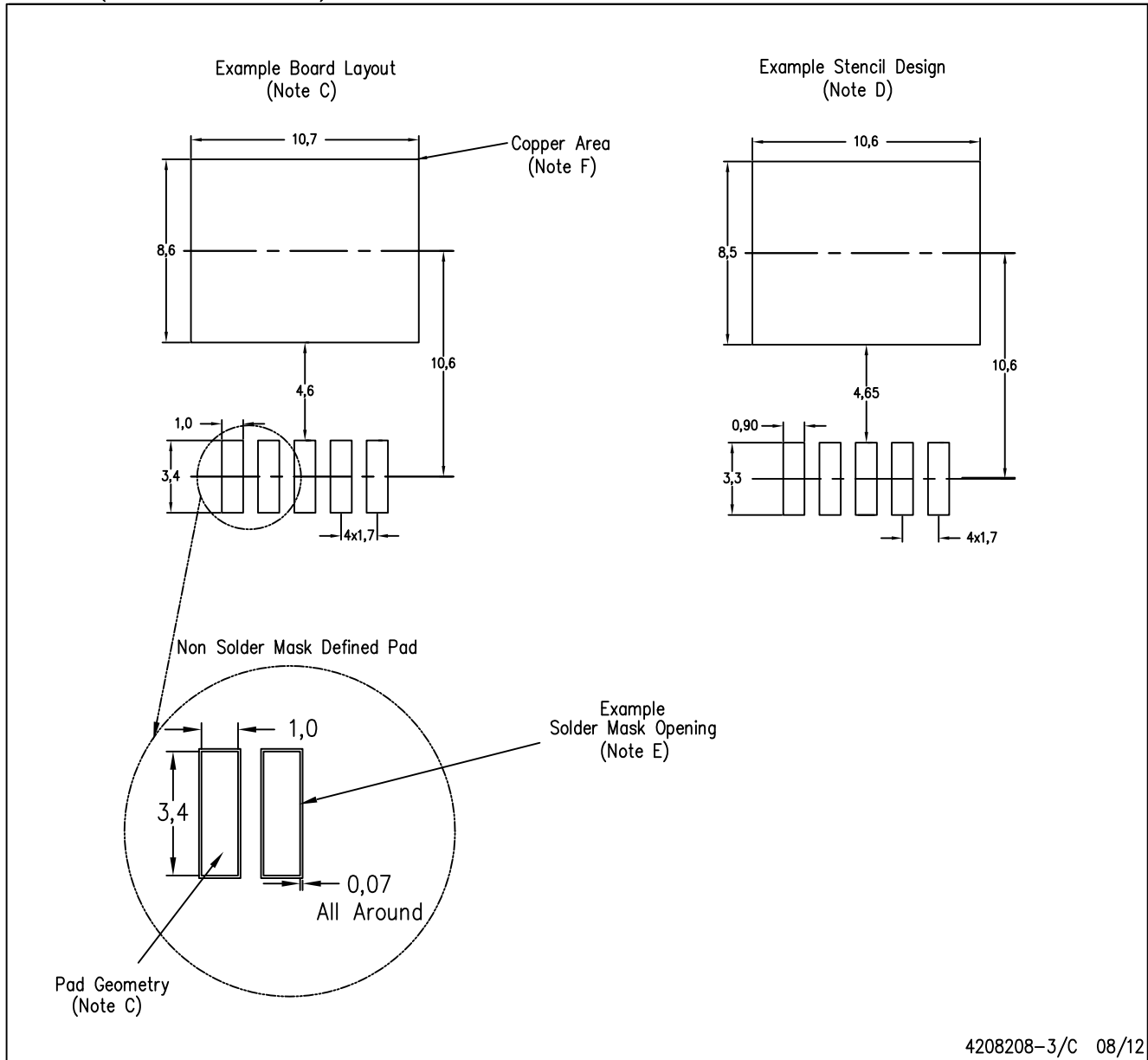
PLASTIC FLANGE-MOUNT PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash or protrusion not to exceed 0.005 (0,13) per side.
- Falls within JEDEC TO-263 variation BA, except minimum lead thickness, maximum seating height, and minimum body length.

KTT (R-PSFM-G5)

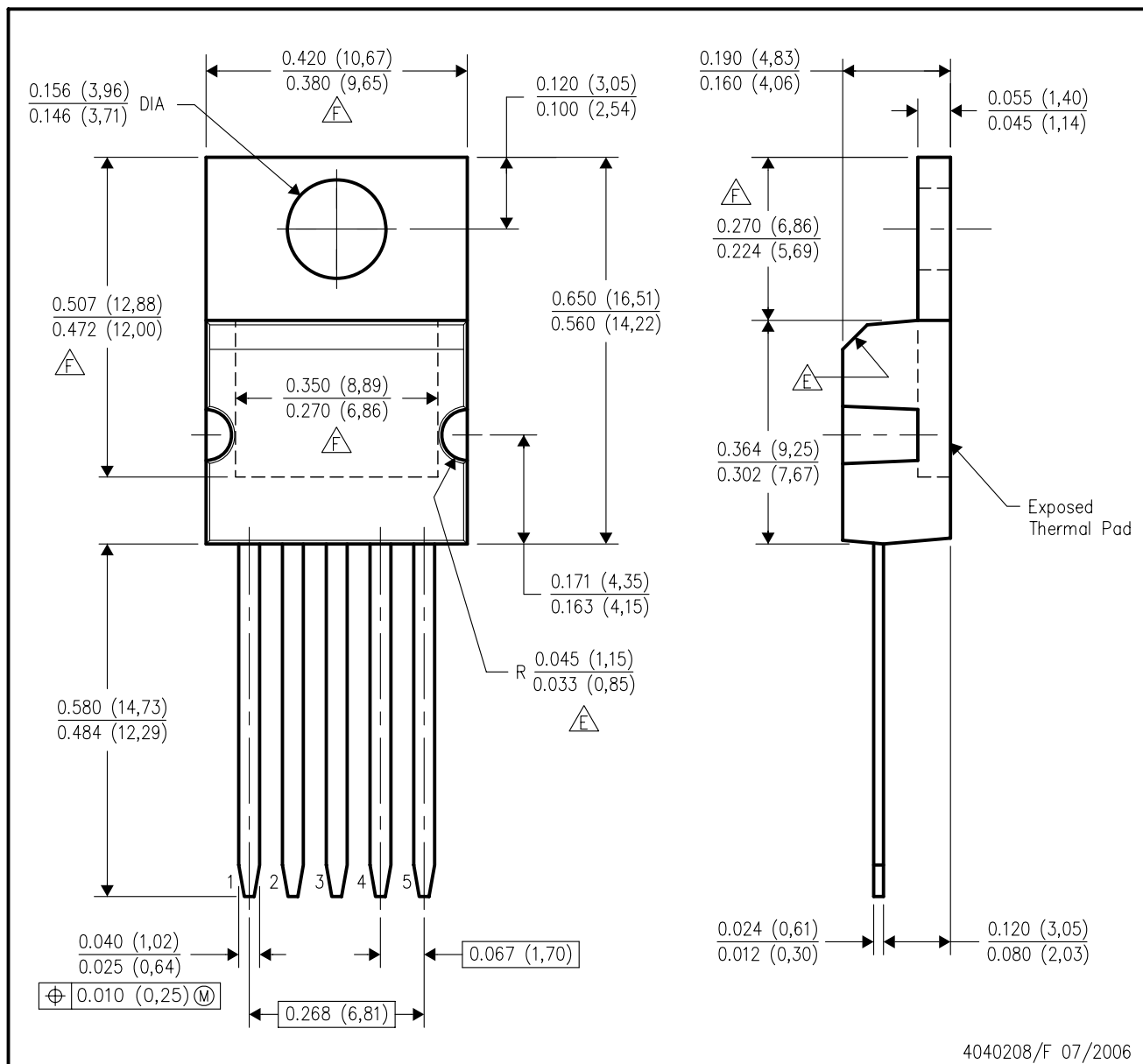
PLASTIC FLANGE-MOUNT PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-SM-782 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.
 - F. This package is designed to be soldered to a thermal pad on the board. Refer to the Product Datasheet for specific thermal information, via requirements, and recommended thermal pad size. For thermal pad sizes larger than shown a solder mask defined pad is recommended in order to maintain the solderable pad geometry while increasing copper area.

KC (R-PSFM-T5)

PLASTIC FLANGE-MOUNT PACKAGE



- NOTES:
- All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice.
 - All lead dimensions apply before solder dip.
 - The center lead is in electrical contact with the mounting tab.
- $\triangle F$ These features are optional.
- $\triangle E$ Thermal pad contour optional within these dimensions.

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